Ordering number: ENN6267

N-Channel Silicon MOSFET



FTD2014

# **Load Switching Applications**

#### **Features**

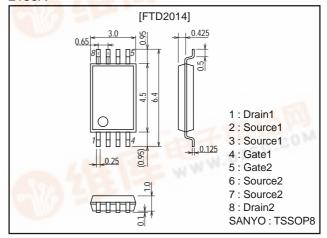
- · Low ON resistance.
- · 2.5V drive.
- · Mounting height 1.1mm.
- · Composite type, facilitating high-density mounting.

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### **Package Dimensions**

unit:mm

2155A



# **Specifications**

Absolute Maximum Ratings at  $Ta = 25^{\circ}C$ 

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	I <sub>D</sub>		4	Α
Drain Current (pulse)	I <sub>DP</sub>	PW≤10µs, duty cycle≤1%	20	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (1000mm <sup>2</sup> ×0.8mm) 1unit	0.8	W
Total Dissipation	PT	Mounted on a ceramic board (1000mm <sup>2</sup> ×0.8mm)	1.3	W
Channel Temperature	Tch	Water State of the Water State of the State	150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 8V$ , $V_{DS}=0$			±10	μΑ
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =4A	7	10	3 3 1 1	S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub> 1	I <sub>D</sub> =4A, V <sub>GS</sub> =4V	HEEL.	32	42	mΩ
	R <sub>DS(on)</sub> 2	I <sub>D</sub> =2A, V <sub>GS</sub> =2.5V	44.74	42	59	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		700		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		200		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		150		pF

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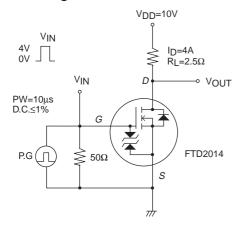
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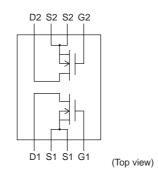
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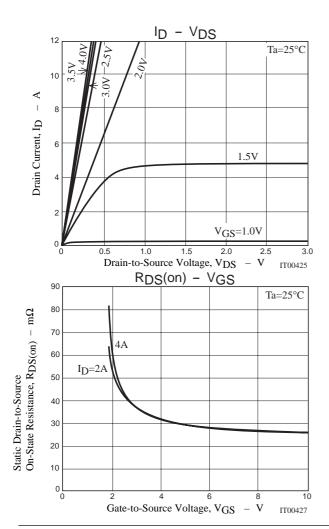
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	t <sub>d(on)</sub>	See Specified Test Circuit		14		ns
Rise Time	t <sub>r</sub>	See Specified Test Circuit		130		ns
Turn-OFF Delay Time	td(off)	See Specified Test Circuit		83		ns
Fall Time	t <sub>f</sub>	See Specified Test Circuit		110		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A		24		nC
Gate-to-Source Charge	Qgs			1.4		nC
Gate-to-Drain "Miller" Charge	Qgd			3.2		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =4A, V <sub>GS</sub> =0		0.85	1.2	V

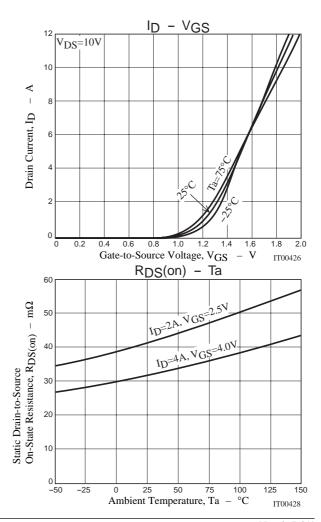
#### **Switching Time Test Circuit**



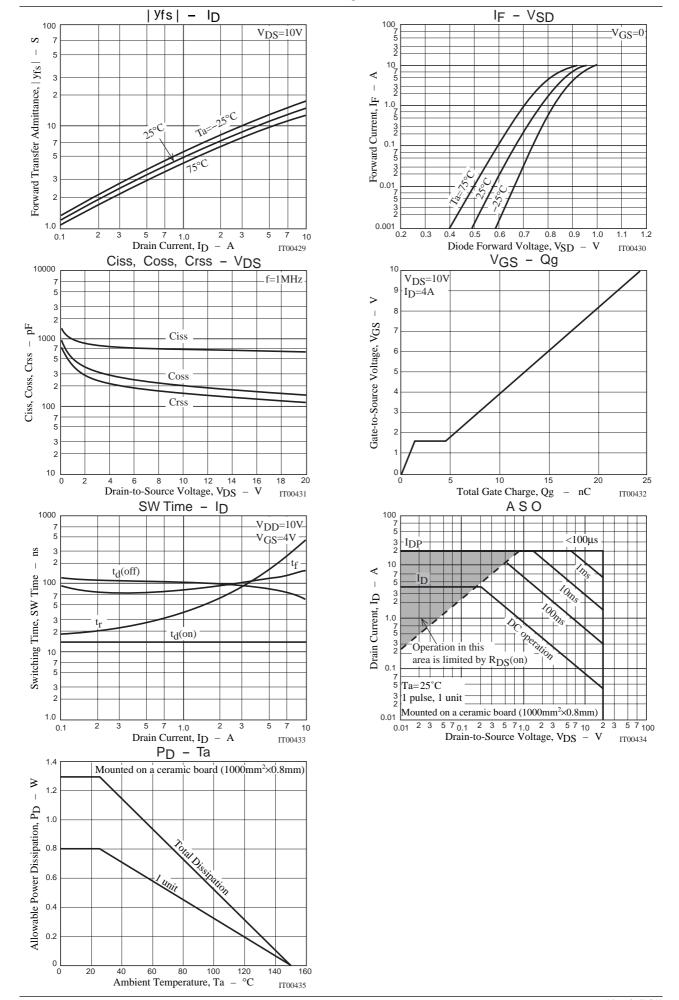
#### **Electrical Connection**







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